DOCKET NO: 250340US0SRD DIV

## IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF

KOICHIRO INOMATA, ET AL. : ATTN: APPLICATION DIVISION

SERIAL NO: NEW APPLICATION :

FILED: HEREWITH

FOR: MAGNETORESISTIVE ELEMENT

AND MAGNETIC MEMORY

**DEVICE** 

## **PRELIMINARY AMENDMENT**

COMMISSIONER FOR PATENTS ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to examination on the merits, please amend the above-identified application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the listing of claims which begins on page 3 of this paper.

Discussion of the Amendment begins on page 6 of this paper.

Remarks begin on page 7 of this paper.